

1 **WHAT IS CLAIMED IS:**

2 1. A microwave power amplifier, comprising:

3 a drive amplifying stage (200) including

4 1) a first power device (213),

5 2) a first RC parallel circuit (217) connected between an input

6 port and a gate of said power device,

7 3) a first shunt resistor (218) connected between a ground and

8 said gate of said first power devices, and

9 4) a negative feedback circuit (207) connected in parallel with

10 said first power device;

11 b) an interstage matching circuit (208) connected in series with said

12 drive amplifying stage; and

13 c) a power amplifying stage (280) including

14 1) a second power device (215) and a third power device (216)

15 connected in parallel with each other and to a power divider (211) and a

16 power combiner (212),

17 2) a second RC parallel circuit (221) connected between said

18 second and third power devices and said interstage matching circuit, and

19 3) a second shunt resistor (222) connected between said ground

20 and said second and third power devices.

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22 2. The microwave power amplifier as claimed in claim 1, wherein said power

23 devices are HEMTs.

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1 3. The microwave power amplifier as claimed in claim 1, wherein said inter- .
2 stage matching circuit utilizes micro-strip lines and open stubs.

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4 4. The microwave power amplifier as claimed in claim 1, wherein said first
5 and second shunt resistors comprise a resistor having micro-strip lines
6 connected to both ends thereof.

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8 5. The microwave power amplifier as claimed in claim 1, wherein said
9 microwave power amplifier further comprises a second drive amplifying stage
10 and a second interstage matching circuit, disposed between said interstage
11 matching circuit and said power amplifying stage.